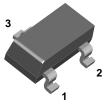
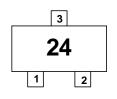


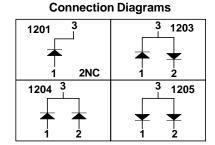
MMBD1201 / 1203 / 1204 / 1205







MARKING MMBD1201 24 MMBD1203 26 MMBD1204 27 MMBD1205 28



Small Signal Diodes

Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Maximum Repetitive Reverse Voltage	100	V
I _{F(AV)}	Average Rectified Forward Current	200	mA
I _{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 2.0	A A
T _{stg}	Storage Temperature Range	-55 to +150	°C
T _J	Operating Junction Temperature	150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Units
P _D	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
V_R	Breakdown Voltage	I _R = 100 μA	100		V
V _F	Forward Voltage	I _F = 1.0 mA I _F = 10 mA I _F = 100 mA I _F = 200 mA I _F = 300 mA	550 660 820 0.87	600 740 920 1.0 1.1	mV mV mV V
I _R	Reverse Current	$V_R = 20 \text{ V}$ $V_R = 50 \text{ V}$ $V_R = 50 \text{ V}$ $V_R = 50 \text{ V}$, $V_A = 150^{\circ}\text{C}$		25 50 5.0	nA nA μA
Ст	Total Capacitance	V _R = 0, f = 1.0 MHz		2.0	pF
t _{rr}	Reverse Recovery Time	$I_F = I_R = 10 \text{ mA}, I_{RR} = 1.0 \text{ mA},$ $R_L = 100 \Omega$		4.0	ns

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¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Small Signal Diode

(continued)

Typical Characteristics

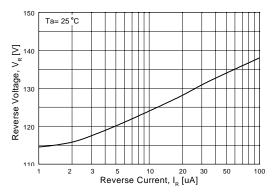


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100uA

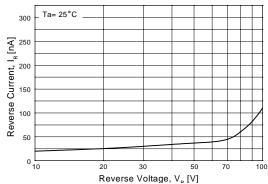


Figure 2. Reverse Current vs Reverse Voltage IR - 10 to 100 V

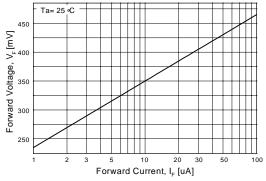


Figure 3. Forward Voltage vs Forward Current VF - 1.0 to 100 uA

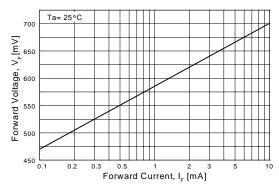


Figure 4. Forward Voltage vs Forward Current VF - 0.1 to 10 mA

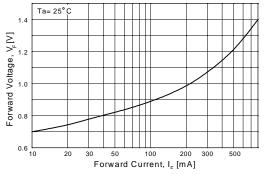


Figure 5. Forward Voltage vs Forward Current VF - 10 - 800 mA

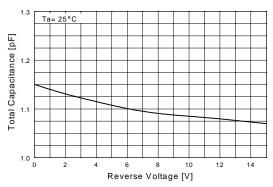


Figure 6. Total Capacitance vs Reverse Voltage

MMBD1200 series, Rev. C

Small Signal Diode

(continued)

Typical Characteristics (continued)

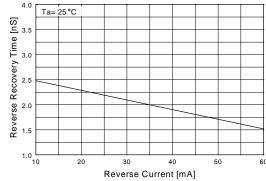


Figure 7. Reverse Recovery Time vs Reverse Current TRR - IR 10 mA vs 60 mA

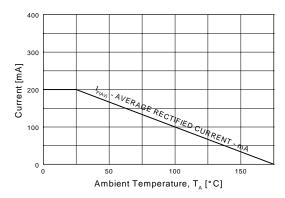


Figure 8. Average Rectified Current ($I_{F(AV)}$) versus Ambient Temperature (T_A)

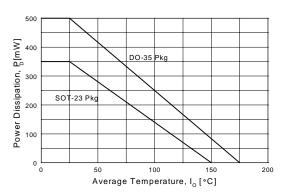


Figure 9. Power Derating Curve

MMBD1200 series, Rev. C

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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